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IN TEE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of: Hitoshi SAOMOTO et al.

Art Unit: 2828

Application Number: 10/592,943 Examiner: Michael Carter

Filed: September 15, 2006 Confirmation Number: 8662

For: SEMICONDUCTOR LASER ELEMENT AND MANUFACTURING METHOD

THEREOF

Attorney Docket Number: 062998

Customer Number: 38834

<u>INFORMATION DISCLOSURE STATEMENT</u> <u>UNDER 37 C.F.R. §1.97(c)(1)/(e)(1)</u>

Commissioner for Patents P. O. Box 1450 Alexandria, VA 22313-1450 March 5, 2008

Sir:

Applicants direct the attention of the Patent and Trademark Office to the documents listed on the attached Form PTO/SB/08. A copy of each non - U.S. document is attached.

This Information Disclosure Statement (IDS) is being submitted after issuance of a first official action on the merits and expiration of the three month period following the filing date or the entry of the national stage for the above-captioned application, but prior to issuance of either a final official action or a Notice of Allowance.

The undersigned hereby certifies that each item of information contained in the IDS was first cited in any communication from a foreign patent office in a counterpart foreign application not more than three months prior to the filing of the IDS. A copy of the foreign communication citing the documents is attached.

Application No.: 10/592,943 Information Disclosure Statement under 1.97(c)(1)

Art Unit: 2828 Attorney Docket No.: 062998

If there are any fees due in connection with the filing of this paper, please charge Deposit Account No. 50-2866.

Respectfully submitted,

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Enclosures: PTO/SB/08

Foreign Communication